

Please delete the Abstract Section of the specification and replace it with the following abstract in clean form. Applicant includes herewith an Attachment for Specification Amendments showing a marked up version of the previous version of the Abstract Section.

ABSTRACT

An organic electroluminescent device comprising: an organic thin-film transistor element including at least an active layer made of an organic material; and an organic electroluminescent element driven by the organic thin-film transistor element.

IN THE CLAIMS

Please cancel claims 1-17 and add the following new claims.

18. (New) An organic electroluminescent device comprising:
an organic thin-film transistor element including at least an active layer made of an organic material; and
an organic electroluminescent element driven by the organic thin-film transistor element.

19. (New) The organic electroluminescent device according to Claim 18, further comprising a substrate, wherein the organic electroluminescent element is provided between the substrate and the organic thin-film transistor element.

20. (New) The organic electroluminescent device according to Claim 18, further comprising a substrate, wherein the organic thin-film transistor element is

AS
provided between the substrate and the organic electroluminescent element.

21. (New) The organic electroluminescent device according to Claim 18, wherein, in each pixel, a total area of a source region area and a drain region area of the organic thin-film transistor element is larger than an area of a region provided with a luminescent material of the organic electroluminescent element.

22. The organic electroluminescent device according to Claim 18, wherein the source and the drain, which constitute the organic thin-film transistor element, have bent parts that face each other at a predetermined spacing.

23. (New) The organic electroluminescent device according to Claim 22, wherein a gate is provided so as to cover the bent parts of the source and the drain.

24. (New) The organic electroluminescent device according to Claim 22, wherein the bent parts of the source and the drain are provided in a comb-shape and face each other at a predetermined spacing.

25. (New) The organic electroluminescent device according to Claim 22, wherein the bent parts of the source and the drain are provided in a spiral-shape and face each other at a predetermined spacing.

26. (New) A method of manufacturing an organic electroluminescent device, comprising:

a step of forming an organic electroluminescent element above a substrate; and
a step of forming an organic thin-film transistor element, for driving the organic

electroluminescent element, above the organic electroluminescent element.

27. (New) A method of manufacturing an organic electroluminescent device, comprising:

a step of forming an organic thin-film transistor element above a substrate; and

a step of forming an organic electroluminescent element, which is driven by the organic thin-film transistor element and performs predetermined display, above the organic thin-film transistor element.

28. (New) The method of manufacturing an organic electroluminescent device according to Claim 26, wherein, in each pixel, a total area of a source region area and drain region area of the organic thin-film transistor element is larger than an area of a region provided with a luminescent material.

29. (New) The method of manufacturing an organic electroluminescent device according to Claim 26, wherein the source and the drain, which constitute the organic thin-film transistor element, have bent parts that face each other at a predetermined spacing.

30. (New) The method of manufacturing an organic electroluminescent device according to Claim 29, wherein a gate is provided so as to cover the bent parts of the source and the drain.

31. (New) The method of manufacturing an organic electroluminescent device, according to Claim 29, wherein the bent parts of the source and the drain are

AS
provided in a comb-shape and face each other at a predetermined spacing.

32. (New) The method of manufacturing an organic electroluminescent device, according to Claim 29, wherein the bent parts of the source and the drain are provided in a spiral-shape and face each other at a predetermined spacing.

33. (New) The method of manufacturing an organic electroluminescent device, according to Claim 26, wherein, at least the organic thin-film transistor and an organic-luminescent layer of the organic electroluminescent element are formed by a liquid-phase process.

34. (New) An electronic apparatus comprising an electroluminescent device according to Claim 18.

35. (New) The method of manufacturing an organic electroluminescent device according to Claim 27, wherein, in each pixel, a total area of a source region area and drain region area of the organic thin-film transistor element is larger than an area of a region provided with a luminescent material.

36. (New) The method of manufacturing an organic electroluminescent device according to Claim 27, wherein the source and the drain, which constitute the organic thin-film transistor element, have bent parts that face each other at a predetermined spacing.

37. (New) The method of manufacturing an organic electroluminescent device according to Claim 36, wherein a gate is provided so as to cover the bent parts

A
of the source and the drain.

38. (New) The method of manufacturing an organic electroluminescent device, according to Claim 36, wherein the bent parts of the source and the drain are provided in a comb-shape and face each other at a predetermined spacing.

sub 21 emv.
39. (New) The method of manufacturing an organic electroluminescent device, according to Claim 36, wherein the bent parts of the source and the drain are provided in a spiral-shape and face each other at a predetermined spacing.

40. (New) The method of manufacturing an organic electroluminescent device, according to Claim 27, wherein, at least the organic thin-film transistor and an organic-luminescent layer of the organic electroluminescent element are formed by a liquid-phase process.